# SN74LVCH8T245 具有可配置电平转换、电压转换和三态输出的 8 位双电源总线收发器

1 特性

- 控制输入（DIR 和 $\overline{OE}$ ）V_{IH} 和 V_{IL} 电平以 V_{CCA} 为基准
- 总线保持数据输入消除了对外部上拉或下拉电阻器的需求
- V_{CC} 隔离
- 完全可配置的双轨设计
- I_{off} 支持局部断电模式运行
- 闩锁性能超过 100mA，符合 JESD 78 II 类规范的要求
- ESD 保护性能超过 JESD 22 规范要求

2 应用

- 个人电子产品
- 工业
- 企业
- 电信

To Seven Other Channels
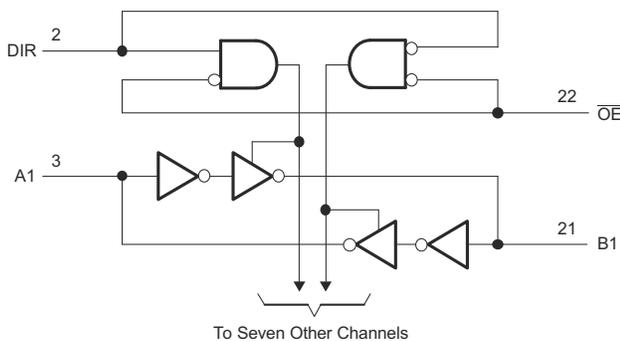
逻辑图（正逻辑）

3 说明

SN74LVCH8T245 是一款采用两个独立可配置电源轨的 8 位同相总线收发器。A 端口设计用于跟踪 V_{CCA}，该端口可接受 1.65V 至 5.5V 范围内的任何电源电压。B 端口设计用于跟踪 V_{CCB}，该端口也可接受 1.65V 至 5.5V 范围内的任何电源电压。这样可实现在 1.8V、2.5V、3.3V 和 5.5V 电压节点之间进行通用低压双向转换。

SN74LVCH8T245 旨在实现两条数据总线间的异步通信。方向控制 (DIR) 输入和输出使能 ($\overline{OE}$) 输入的逻辑电平会激活 B 端口输出或 A 端口输出，或者将两个输出端口都置于高阻抗状态。当 B 端口输出被激活时，此器件将数据从 A 总线发送到 B 总线，而当 A 端口输出被激活时，此器件将数据从 B 总线发送到 A 总线。A 端口和 B 端口上的输入电路始终处于运行状态。

有源总线保持电路会将未使用或未驱动的输入保持在有效逻辑状态。不建议在总线保持电路上使用上拉或下拉电阻器。该器件完全符合使用 I_{off} 的部分断电应用的规范要求。I_{off} 电路禁用输出，从而可防止破坏性电流从该器件回流。V_{CC} 隔离特性可确保 V_{CCA} 或 V_{CCB} 接地时，输出都处于高阻抗状态。为了确保加电或断电期间呈高阻态，$\overline{OE}$ 应通过一个上拉电阻器被连接至 V_{CCA}；该电阻器的最小值由驱动器的电流吸入能力来决定。

SN74LVCH8T245 旨在使控制引脚（DIR 和 $\overline{OE}$）以 V_{CCA} 为基准。

封装信息[1]

器件型号	封装	封装尺寸（标称值）
SN74LVCH8T245	DB（SSOP，24）	8.65mm × 3.90mm
	DGV（TVSOP，24）	5.00mm × 4.40mm
	PW（TSSOP，24）	7.80mm × 4.40mm
	RHL（VQFN，24）	5.50mm × 3.50mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

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4 Revision History

注：以前版本的页码可能与当前版本的页码不同

5 Pin Configuration and Functions

图 5-1. DB, DGV, or PW Packages, 24-Pin SSOP, TVSOP, or TSSOP (Top View)
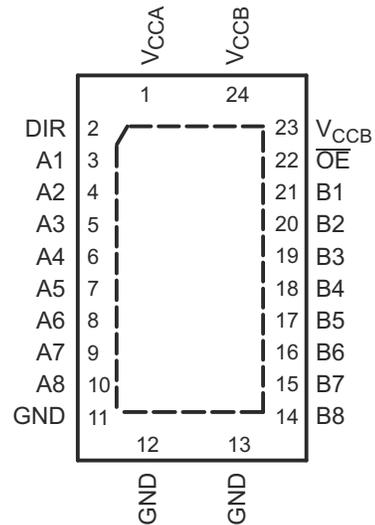
图 5-2. RHL Package, 24-Pin VQFN (Top View)

表 5-1. Pin Functions

PIN			TYPE[1]	DESCRIPTION
NAME	SSOP, TVSOP, TSSOP	VQFN		
A1	3	3	I/O	Input/output A1. Referenced to V_{CCA}.
A2	4	4	I/O	Input/output A2. Referenced to V_{CCA}.
A3	5	5	I/O	Input/output A3. Referenced to V_{CCA}.
A4	6	6	I/O	Input/output A4. Referenced to V_{CCA}.
A5	7	7	I/O	Input/output A5. Referenced to V_{CCA}.
A6	8	8	I/O	Input/output A6. Referenced to V_{CCA}.
A7	9	9	I/O	Input/output A7. Referenced to V_{CCA}.
A8	10	10	I/O	Input/output A8. Referenced to V_{CCA}.
B1	21	21	I/O	Input/output B1. Referenced to V_{CCB}.
B2	20	20	I/O	Input/output B2. Referenced to V_{CCB}.
B3	19	19	I/O	Input/output B3. Referenced to V_{CCB}.
B4	18	18	I/O	Input/output B4. Referenced to V_{CCB}.
B5	17	17	I/O	Input/output B5. Referenced to V_{CCB}.
B6	16	16	I/O	Input/output B6. Referenced to V_{CCB}.
B7	15	15	I/O	Input/output B7. Referenced to V_{CCB}.
B8	14	14	I/O	Input/output B8. Referenced to V_{CCB}.
DIR	2	2	I	Direction-control signal. Referenced to V_{CCA}.
$\overline{OE}$	22	22	I	3-state output-mode enables. Pull $\overline{OE}$ high to place all outputs in 3-state mode. Referenced to V_{CCA}.
V_{CCA}	1	1	—	A-port supply voltage. 1.65 V $\leqslant V_{CCA} \leqslant$ 5.5 V
V_{CCB}	23, 24	23, 24	—	B-port supply voltage. 1.65 V $\leqslant V_{CCA} \leqslant$ 5.5 V
GND	11, 12, 13	11, 12, 13	—	Ground

(1) I = input, O = output

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[1]

		MIN	MAX	UNIT
Supply voltage	V_{CCA} and V_{CCB}	−0.5	6.5	V
Input voltage[2]	I/O ports (A port)	−0.5	6.5	V
	I/O ports (B port)	−0.5	6.5	
	Control inputs	−0.5	6.5	
Voltage range applied to any output in the high-impedance or power-off state[2]	A port	−0.5	6.5	V
	B port	−0.5	6.5	
Voltage range applied to any output in the high or low state[2] [3]	A port	−0.5	V_{CCA} + 0.5	V
	B port	−0.5	V_{CCB} + 0.5	
Input clamp current	V_I < 0		−50	mA
Output clamp current	V_O < 0		−50	mA
Continuous output current, I_O			±50	mA
Continuous through current	V_{CCA}, V_{CCB}, and GND		±100	mA
Junction temperature, T_J		−40	150	°C
Storage temperature, T_{stg}		−65	150	°C

(1)   Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under 节 *6.3*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2)   The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
(3)   The output positive-voltage rating may be exceeded up to 6.5 V maximum if the output current rating is observed.

6.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$ Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001[1]	±4000	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101[2]	±1000	
	Machine model (MM)	±200	

(1)   JEDEC document JEP155 states that 500 V HBM allows safe manufacturing with a standard ESD control process.
(2)   JEDEC document JEP157 states that 250 V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)[1] [2] [3]

				MIN	MAX	UNIT
V_{CCA}	Supply voltage			1.65	5.5	V
V_{CCB}				1.65	5.5	
V_{IH}	High-level input voltage[1]	Data inputs[4]	V_{CCI} = 1.65 V to 4.5 V	V_{CCI} × 0.65		V
			V_{CCI} = 2.3 V to 2.7 V	1.7		
			V_{CCI} = 3 V to 3.6 V	2		
			V_{CCI} = 4.5 V to 5.5 V	V_{CCI} × 0.7		
V_{IL}	Low-level input voltage[1]	Data inputs[4]	V_{CCI} = 1.65 V to 4.5 V		V_{CCI} × 0.35	V
			V_{CCI} = 2.3 V to 2.7 V		0.7	
			V_{CCI} = 3 V to 3.6 V		0.8	
			V_{CCI} = 4.5 V to 5.5 V		V_{CCI} × 0.3	

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6.3 Recommended Operating Conditions (continued)

over operating free-air temperature range (unless otherwise noted)[1] [2] [3]

				MIN	MAX	UNIT
V_{IH}	High-level input voltage	Control inputs (referenced to V_{CCA})[5]	V_{CCI} = 1.65 V to 4.5 V	$V_{CCA} \times 0.65$		V
			V_{CCI} = 2.3 V to 2.7 V	1.7		
			V_{CCI} = 3 V to 3.6 V	2		
			V_{CCI} = 4.5 V to 5.5 V	$V_{CCA} \times 0.7$		
V_{IL}	Low-level input voltage	Control inputs (referenced to V_{CCA})[5]	V_{CCI} = 1.65 V to 4.5 V		$V_{CCA} \times 0.35$	V
			V_{CCI} = 2.3 V to 2.7 V		0.7	
			V_{CCI} = 3 V to 3.6 V		0.8	
			V_{CCI} = 4.5 V to 5.5 V		$V_{CCA} \times 0.3$	
V_I	Input voltage	Control inputs[3]		0	5.5	V
$V_{I/O}$	Input/output voltage[2]	Active state		0	V_{CCO}	V
		3-State		0	5.5	
I_{OH}	High-level output current	V_{CCO} = 1.65 V to 4.5 V			-4	mA
		V_{CCO} = 2.3 V to 2.7 V			-8	
		V_{CCO} = 3 V to 3.6 V			-24	
		V_{CCO} = 4.5 V to 5.5 V			-32	
I_{OL}	Low-level output current	V_{CCO} = 1.65 V to 4.5 V			4	mA
		V_{CCO} = 2.3 V to 2.7 V			8	
		V_{CCO} = 3 V to 3.6 V			24	
		V_{CCO} = 4.5 V to 5.5 V			32	
$\Delta t / \Delta v$	Input transition rise or fall rate	Data inputs	V_{CCI} = 1.65 V to 4.5 V		20	ns/V
			V_{CCI} = 2.3 V to 2.7 V		20	
			V_{CCI} = 3 V to 3.6 V		10	
			V_{CCI} = 4.5 V to 5.5 V		5	
T_A	Operating free-air temperature			-40	85	°C

(1) V_{CCI} is the V_{CC} associated with the data input port.
(2) V_{CCO} is the V_{CC} associated with the output port.
(3) All unused control inputs of the device must be held at V_{CCA} or GND to ensure proper device operation and minimize power consumption. See *Implications of Slow or Floating CMOS Inputs*, SCBA004.
(4) For V_{CCI} values not specified in the data sheet, V_{IH} min = $V_{CCI} \times 0.7$ V, V_{IL} (max) = $V_{CCI} \times 0.3$ V.
(5) For V_{CCA} values not specified in the data sheet, V_{IH} min = $V_{CCA} \times 0.7$ V, V_{IL} (max) = $V_{CCA} \times 0.3$ V.

6.4 Thermal Information

		SN74LVCH8T245				UNIT
THERMAL METRIC[1]		DB (SSOP)	DGV (TVSOP)	PW (TSSOP)	RHL (VQFN)	
		24 PINS	24 PINS	24 PINS	24 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	88.5	91.1	100.6	37.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	48.7	23.7	44.7	38.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	44.1	44.5	55.8	15.2	°C/W
ψ_{JT}	Junction-to-top characterization parameter	12.8	0.6	6.8	0.7	°C/W
ψ_{JB}	Junction-to-board characterization parameter	43.6	44.1	55.4	15.2	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	—	—	—	4.3	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, SPRA953.

6.5 Electrical Characteristics

All typical limits apply over T_A = 25°C, and all maximum and minimum limits apply over T_A = ‒40°C to 85°C (unless otherwise noted).[1] [2]

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{OH}	High-level output voltage[1]	I_{OH} = ‒100 µA, $V_I = V_{IH}$	$V_{CCA} = V_{CCB}$ = 1.65 V to 4.5 V	V_{CCO} = 0.1			V
		I_{OH} = ‒4 mA, $V_I = V_{IH}$	$V_{CCA} = V_{CCB}$ = 1.65 V	1.2			
		I_{OH} = ‒8 mA, $V_I = V_{IH}$	$V_{CCA} = V_{CCB}$ = 2.3 V	1.9			
		I_{OH} = ‒24 mA, $V_I = V_{IH}$	$V_{CCA} = V_{CCB}$ = 3 V	2.4			
		I_{OH} = ‒32 mA, $V_I = V_{IH}$	$V_{CCA} = V_{CCB}$ = 4.5 V	3.8			
V_{OL}	Low-level output voltage	I_{OL} = 100 µA, $V_I = V_{IL}$	$V_{CCA} = V_{CCB}$ = 1.65 V to 4.5 V			0.1	V
		I_{OL} = 4 mA, $V_I = V_{IL}$	$V_{CCA} = V_{CCB}$ = 1.65 V			0.45	
		I_{OL} = 8 mA, $V_I = V_{IL}$	$V_{CCA} = V_{CCB}$ = 2.3 V			0.3	
		I_{OL} = 24 mA, $V_I = V_{IL}$	$V_{CCA} = V_{CCB}$ = 3 V			0.55	
		I_{OL} = 32 mA, $V_I = V_{IL}$	$V_{CCA} = V_{CCB}$ = 4.5 V			0.55	
I_I	Control inputs	$V_I = V_{CCA}$ or GND	$V_{CCA} = V_{CCB}$ = 1.65 V to 4.5 V		±0.5	±2	µA
I_{BHL} [3]	Bus-hold low sustaining current	V_I = 0.58 V	$V_{CCA} = V_{CCB}$ = 1.65 V	15			µA
		V_I = 0.7 V	$V_{CCA} = V_{CCB}$ = 2.3 V	45			
		V_I = 0.8 V	$V_{CCA} = V_{CCB}$ = 3 V	75			
		V_I = 1.35 V	$V_{CCA} = V_{CCB}$ = 4.5 V	100			
I_{BHH} [4]	Bus-hold high sustaining current	V_I = 1.07 V	$V_{CCA} = V_{CCB}$ = 1.65 V	‒15			µA
		V_I = 1.7 V	$V_{CCA} = V_{CCB}$ = 2.3 V	‒45			
		V_I = 2 V	$V_{CCA} = V_{CCB}$ = 3 V	‒75			
		V_I = 3.15 V	$V_{CCA} = V_{CCB}$ = 4.5 V	‒100			
I_{BHLO} [5]	Bus-hold low overdrive current	V_I = 0 to V_{CC}	$V_{CCA} = V_{CCB}$ = 1.95 V	200			µA
			$V_{CCA} = V_{CCB}$ = 2.7 V	300			
			$V_{CCA} = V_{CCB}$ = 3.6 V	500			
			$V_{CCA} = V_{CCB}$ = 5.5 V	900			
I_{BHHO} [6]	Bus-hold high overdrive current	V_I = 0 to V_{CC}	$V_{CCA} = V_{CCB}$ = 1.95 V	‒200			µA
			$V_{CCA} = V_{CCB}$ = 2.7 V	‒300			
			$V_{CCA} = V_{CCB}$ = 3.6 V	‒500			
			$V_{CCA} = V_{CCB}$ = 5.5 V	‒900			
I_{off}	Input and output power-off leakage current	V_I or V_O = 0 to 5.5 V	V_{CCA} = 0 V, V_{CCB} = 0 to 5.5 V	A Port		±0.5	±2	µA
			V_{CCA} = 0 to 5.5 V, V_{CCB} = 0 V	B Port		±0.5	±2	
I_{OZ}	Off-state output current	$V_O = V_{CCO}$ or GND, $V_I = V_{CCI}$ or GND	$\overline{OE} = V_{IH}$	$V_{CCA} = V_{CCB}$ = 1.65 V to 4.5 V	A Port, B Port			±2	µA
			$\overline{OE}$ = X	V_{CCA} = 0 V, V_{CCB} = 5.5 V	B Port			±2	
				V_{CCA} = 5.5 V, V_{CCB} = 0 V	A Port			±2	
I_{CCA}	Supply current A port	$V_I = V_{CCI}$ or GND, I_O = 0	$V_{CCA} = V_{CCB}$ = 1.65 V to 4.5 V			20	µA
			V_{CCA} = 5 V, V_{CCB} = 0 V			20	
			V_{CCA} = 0 V, V_{CCB} = 5 V			‒2	
I_{CCB}	Supply current B port	$V_I = V_{CCI}$ or GND, I_O = 0	$V_{CCA} = V_{CCB}$ = 1.65 V to 4.5 V			20	µA
			V_{CCA} = 5 V, V_{CCB} = 0 V			‒2	
			V_{CCA} = 0 V, V_{CCB} = 5 V			20	

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6.5 Electrical Characteristics (continued)

All typical limits apply over T_A = 25°C, and all maximum and minimum limits apply over T_A = –40°C to 85°C (unless otherwise noted).[1] [2]

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
	Combined supply current	V_I = V_{CCI} or GND, I_O = 0	V_{CCA} = V_{CCB} = 1.65 V to 4.5 V			30	μ A
Δ I_{CCA}	Supply-current change DIR	DIR at V_{CCA} - 0.6 V, B port = open, A port at V_{CCA} or GND	V_{CCA} = V_{CCB} = 3 to 5.5 V			50	μ A
C_i	Input capacitance control inputs	V_I = V_{CCA} or GND	V_{CCA} = V_{CCB} = 3.3 V		4	5	pF
C_{io}	Input and output capacitance A or B port	V_O = $V_{CCA/B}$ or GND	V_{CCA} = V_{CCB} = 3.3 V		8.5	10	pF

(1) V_{CCO} is the V_{CC} associated with the output port.
(2) V_{CCI} is the V_{CC} associated with the input port.
(3)   The bus-hold circuit can sink at least the minimum low sustaining current at the V_{IL} maximum. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} maximum.
(4)   The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to V_{IH} min.
(5)   An external driver must source at least I_{BHLO} to switch this node from low to high.
(6)   An external driver must sink at least I_{BHHO} to switch this node from high to low.

6.6 Switching Characteristics: V_{CCA} = 1.8 V ± 0.15 V

over recommended operating free-air temperature range, V_{CCA} = 1.8 V ± 0.15 V (unless otherwise noted) (see 图 7-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
t_{PLH}, t_{PHL}	A	B	V_{CCB} = 1.8 V ± 0.15 V	1.7	21.9	ns
			V_{CCB} = 2.5 V ± 0.2 V	1.3	9.2	
			V_{CCB} = 3.3 V ± 0.3 V	1	7.4	
			V_{CCB} = 5 V ± 0.5 V	0.4	7.1	
t_{PLH}, t_{PHL}	B	A	V_{CCB} = 1.8 V ± 0.15 V	0.9	23.8	ns
			V_{CCB} = 2.5 V ± 0.2 V	0.8	23.6	
			V_{CCB} = 3.3 V ± 0.3 V	0.7	23.4	
			V_{CCB} = 5 V ± 0.5 V	0.7	23.4	
t_{PHZ}, t_{PLZ}	$\overline{OE}$	A	V_{CCB} = 1.8 V ± 0.15 V	1.5	29.6	ns
			V_{CCB} = 2.5 V ± 0.2 V	1.5	29.4	
			V_{CCB} = 3.3 V ± 0.3 V	1.5	29.3	
			V_{CCB} = 5 V ± 0.5 V	1.4	29.2	
t_{PHZ}, t_{PLZ}	$\overline{OE}$	B	V_{CCB} = 1.8 V ± 0.15 V	2.4	32.2	ns
			V_{CCB} = 2.5 V ± 0.2 V	1.9	13.1	
			V_{CCB} = 3.3 V ± 0.3 V	1.7	12	
			V_{CCB} = 5 V ± 0.5 V	1.3	10.3	
t_{PZH}, t_{PZL}	$\overline{OE}$	A	V_{CCB} = 1.8 V ± 0.15 V	0.4	24	ns
			V_{CCB} = 2.5 V ± 0.2 V	0.4	23.8	
			V_{CCB} = 3.3 V ± 0.3 V	0.4	23.7	
			V_{CCB} = 5 V ± 0.5 V	0.4	23.7	
t_{PZH}, t_{PZL}	$\overline{OE}$	B	V_{CCB} = 1.8 V ± 0.15 V	1.8	32	ns
			V_{CCB} = 2.5 V ± 0.2 V	1.5	16	
			V_{CCB} = 3.3 V ± 0.3 V	1.2	12.6	
			V_{CCB} = 5 V ± 0.5 V	0.9	10.8	

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6.7 Switching Characteristics: V_{CCA} = 2.5 V ± 0.2 V

over recommended operating free-air temperature range, V_{CCA} = 2.5 V ± 0.2 V (unless otherwise noted) (see 图 7-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
t_{PLH}, t_{PHL}	A	B	V_{CCB} = 1.8 V ± 0.15 V	1.5	21.4	ns
			V_{CCB} = 2.5 V ± 0.2 V	1.2	9	
			V_{CCB} = 3.3 V ± 0.3 V	0.8	6.2	
			V_{CCB} = 5 V ± 0.5 V	0.6	4.8	
t_{PLH}, t_{PHL}	B	A	V_{CCB} = 1.8 V ± 0.15 V	1.2	9.3	ns
			V_{CCB} = 2.5 V ± 0.2 V	1	9.1	
			V_{CCB} = 3.3 V ± 0.3 V	1	8.9	
			V_{CCB} = 5 V ± 0.5 V	0.9	8.8	
t_{PHZ}, t_{PLZ}	$\overline{OE}$	A	V_{CCB} = 1.8 V ± 0.15 V	1.4	9	ns
			V_{CCB} = 2.5 V ± 0.2 V	1.4	9	
			V_{CCB} = 3.3 V ± 0.3 V	1.4	9	
			V_{CCB} = 5 V ± 0.5 V	1.4	9	
t_{PHZ}, t_{PLZ}	$\overline{OE}$	B	V_{CCB} = 1.8 V ± 0.15 V	2.3	29.6	ns
			V_{CCB} = 2.5 V ± 0.2 V	1.8	11	
			V_{CCB} = 3.3 V ± 0.3 V	1.7	9.3	
			V_{CCB} = 5 V ± 0.5 V	0.9	6.9	
t_{PZH}, t_{PZL}	$\overline{OE}$	A	V_{CCB} = 1.8 V ± 0.15 V	1	10.9	ns
			V_{CCB} = 2.5 V ± 0.2 V	1	10.9	
			V_{CCB} = 3.3 V ± 0.3 V	1	10.9	
			V_{CCB} = 5 V ± 0.5 V	1	10.9	
t_{PZH}, t_{PZL}	$\overline{OE}$	B	V_{CCB} = 1.8 V ± 0.15 V	1.7	28.2	ns
			V_{CCB} = 2.5 V ± 0.2 V	1.5	12.9	
			V_{CCB} = 3.3 V ± 0.3 V	1.2	9.4	
			V_{CCB} = 5 V ± 0.5 V	1	6.9	

Product Folder Links: *SN74LVCH8T245*

6.8 Switching Characteristics: V$_{CCA}$ = 3.3 V ± 0.3 V

over recommended operating free-air temperature range, V$_{CCA}$ = 3.3 V ± 0.3 V (unless otherwise noted) (see 图 7-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
t$_{PLH}$, t$_{PHL}$	A	B	V$_{CCB}$ = 1.8 V ± 0.15 V	1.5	21.2	ns
			V$_{CCB}$ = 2.5 V ± 0.2 V	1.1	8.8	
			V$_{CCB}$ = 3.3 V ± 0.3 V	0.8	6.2	
			V$_{CCB}$ = 5 V ± 0.5 V	0.5	4.4	
t$_{PLH}$, t$_{PHL}$	B	A	V$_{CCB}$ = 1.8 V ± 0.15 V	0.8	7.2	ns
			V$_{CCB}$ = 2.5 V ± 0.2 V	0.8	6.2	
			V$_{CCB}$ = 3.3 V ± 0.3 V	0.7	6.1	
			V$_{CCB}$ = 5 V ± 0.5 V	0.6	6	
t$_{PHZ}$, t$_{PLZ}$	$\overline{OE}$	A	V$_{CCB}$ = 1.8 V ± 0.15 V	1.6	8.2	ns
			V$_{CCB}$ = 2.5 V ± 0.2 V	1.6	8.2	
			V$_{CCB}$ = 3.3 V ± 0.3 V	1.6	8.2	
			V$_{CCB}$ = 5 V ± 0.5 V	1.6	8.2	
t$_{PHZ}$, t$_{PLZ}$	$\overline{OE}$	B	V$_{CCB}$ = 1.8 V ± 0.15 V	2.1	29	ns
			V$_{CCB}$ = 2.5 V ± 0.2 V	1.7	10.3	
			V$_{CCB}$ = 3.3 V ± 0.3 V	1.5	8.6	
			V$_{CCB}$ = 5 V ± 0.5 V	0.8	6.3	
t$_{PZH}$, t$_{PZL}$	$\overline{OE}$	A	V$_{CCB}$ = 1.8 V ± 0.15 V	0.8	8.1	ns
			V$_{CCB}$ = 2.5 V ± 0.2 V	0.8	8.1	
			V$_{CCB}$ = 3.3 V ± 0.3 V	0.8	8.1	
			V$_{CCB}$ = 5 V ± 0.5 V	0.8	8.1	
t$_{PZH}$, t$_{PZL}$	$\overline{OE}$	B	V$_{CCB}$ = 1.8 V ± 0.15 V	1.8	27.7	ns
			V$_{CCB}$ = 2.5 V ± 0.2 V	1.4	12.4	
			V$_{CCB}$ = 3.3 V ± 0.3 V	1.1	8.5	
			V$_{CCB}$ = 5 V ± 0.5 V	0.9	6.4	

Product Folder Links: *SN74LVCH8T245*

6.9 Switching Characteristics: V_{CCA} = 5 V ± 0.5 V

over recommended operating free-air temperature range, V_{CCA} = 5 V ± 0.5 V (unless otherwise noted) (see 图 7-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
t_{PLH}, t_{PHL}	A	B	V_{CCB} = 1.8 V ± 0.15 V	1.5	21.4	ns
			V_{CCB} = 2.5 V ± 0.2 V	1	8.8	
			V_{CCB} = 3.3 V ± 0.3 V	0.7	6	
			V_{CCB} = 5 V ± 0.5 V	0.4	4.2	
t_{PLH}, t_{PHL}	B	A	V_{CCB} = 1.8 V ± 0.15 V	0.7	7	ns
			V_{CCB} = 2.5 V ± 0.2 V	0.4	4.8	
			V_{CCB} = 3.3 V ± 0.3 V	0.3	4.5	
			V_{CCB} = 5 V ± 0.5 V	0.3	4.3	
t_{PHZ}, t_{PLZ}	$\overline{OE}$	A	V_{CCB} = 1.8 V ± 0.15 V	0.3	5.4	ns
			V_{CCB} = 2.5 V ± 0.2 V	0.3	5.4	
			V_{CCB} = 3.3 V ± 0.3 V	0.3	5.4	
			V_{CCB} = 5 V ± 0.5 V	0.3	5.4	
t_{PHZ}, t_{PLZ}	$\overline{OE}$	B	V_{CCB} = 1.8 V ± 0.15 V	2	28.7	ns
			V_{CCB} = 2.5 V ± 0.2 V	1.6	9.7	
			V_{CCB} = 3.3 V ± 0.3 V	1.4	8	
			V_{CCB} = 5 V ± 0.5 V	0.7	5.7	
t_{PZH}, t_{PZL}	$\overline{OE}$	A	V_{CCB} = 1.8 V ± 0.15 V	0.7	6.4	ns
			V_{CCB} = 2.5 V ± 0.2 V	0.7	6.4	
			V_{CCB} = 3.3 V ± 0.3 V	0.7	6.4	
			V_{CCB} = 5 V ± 0.5 V	0.7	6.4	
t_{PZH}, t_{PZL}	$\overline{OE}$	B	V_{CCB} = 1.8 V ± 0.15 V	1.5	27.6	ns
			V_{CCB} = 2.5 V ± 0.2 V	1.3	11.4	
			V_{CCB} = 3.3 V ± 0.3 V	1	8.1	
			V_{CCB} = 5 V ± 0.5 V	0.9	6.5	

Product Folder Links: *SN74LVCH8T245*

6.10 Operating Characteristics

$T_A = 25°C$

PARAMETER[1]		TEST CONDITIONS		TYP	UNIT
C_{pdA} [2]	A-port input, B-port output	$C_L = 0$, f = 10 MHz, $t_r = t_f = 1$ ns	$V_{CCA} = V_{CCB} = 1.8$ V	2	pF
			$V_{CCA} = V_{CCB} = 2.5$ V	2	
			$V_{CCA} = V_{CCB} = 3.3$ V	2	
			$V_{CCA} = V_{CCB} = 5$ V	3	
	B-port input, A-port output	$C_L = 0$, f = 10 MHz, $t_r = t_f = 1$ ns	$V_{CCA} = V_{CCB} = 1.8$ V	12	
			$V_{CCA} = V_{CCB} = 2.5$ V	13	
			$V_{CCA} = V_{CCB} = 3.3$ V	13	
			$V_{CCA} = V_{CCB} = 5$ V	16	
C_{pdB} [2]	A-port input, B-port output	$C_L = 0$, f = 10 MHz, $t_r = t_f = 1$ ns	$V_{CCA} = V_{CCB} = 1.8$ V	13	pF
			$V_{CCA} = V_{CCB} = 2.5$ V	13	
			$V_{CCA} = V_{CCB} = 3.3$ V	14	
			$V_{CCA} = V_{CCB} = 5$ V	16	
	B-port input, A-port output	$C_L = 0$, f = 10 MHz, $t_r = t_f = 1$ ns	$V_{CCA} = V_{CCB} = 1.8$ V	2	
			$V_{CCA} = V_{CCB} = 2.5$ V	2	
			$V_{CCA} = V_{CCB} = 3.3$ V	2	
			$V_{CCA} = V_{CCB} = 5$ V	3	

(1)   See *CMOS Power Consumption and Cpd Calculation*, SCAA035.
(2)   Power dissipation capacitance per transceiver.

## 6.11 Typical Characteristics

图 6-1. Voltage vs Current

图 6-2. Voltage vs Current

Product Folder Links: *SN74LVCH8T245*
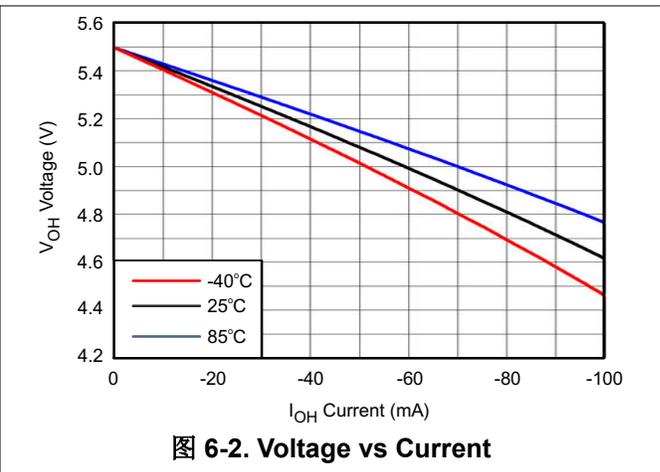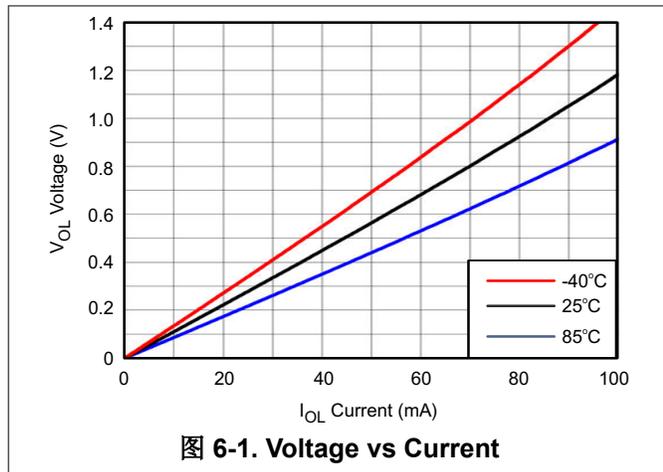
7 Parameter Measurement Information

LOAD CIRCUIT
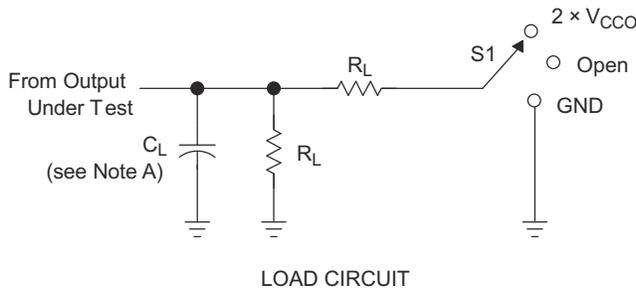
TEST	S1
t_{pd}	Open
t_{PLZ}/t_{PZL}	$2 \times V_{CCO}$
t_{PHZ}/t_{PZH}	GND

V_{CCO}	C_L	R_L	V_{TP}
1.8 V ± 0.15 V	15 pF	2 kW	0.15 V
2.5 V ± 0.2 V	15 pF	2 kW	0.15 V
3.3 V ± 0.3 V	15 pF	2 kW	0.3 V
5 V ± 0.5 V	15 pF	2 kW	0.3 V

VOLTAGE WAVEFORMS
PULSE DURATION

VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES

VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
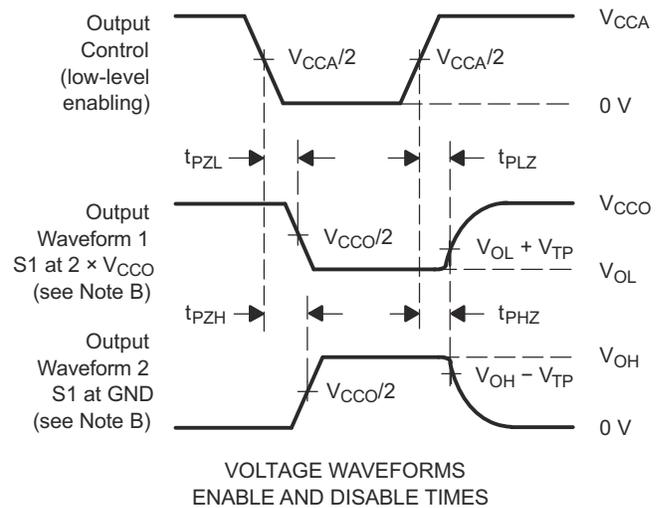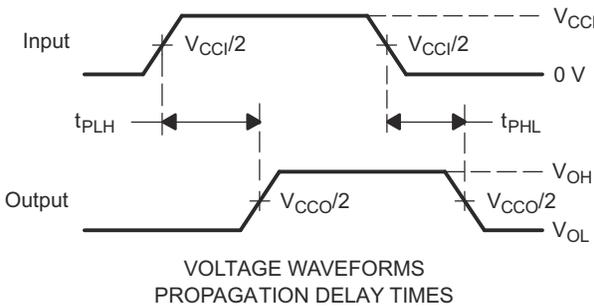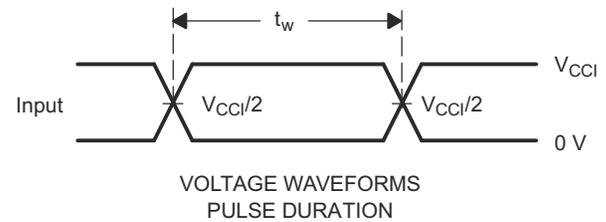
NOTES:
A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR   10 MHz, Z_O = 50 W, dv/dt ≥ 1 V/ns.
D. The outputs are measured one at a time, with one transition per measurement.
E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
F. t_{PZL} and t_{PZH} are the same as t_{en}.
G. t_{PLH} and t_{PHL} are the same as t_{pd}.
H. V_{CCI} is the V_{CC} associated with the input port.
I. V_{CCO} is the V_{CC} associated with the output port.
J. All parameters and waveforms are not applicable to all devices.

图 7-1. Load Circuit and Voltage Waveforms

Product Folder Links: *SN74LVCH8T245*

8 Detailed Description

8.1 Overview

The SN74LVCH8T245 is an 8-bit, dual supply noninverting voltage level translator. Pins A1 through A4, and the control pins (DIR and $\overline{OE}$) are referenced to V_{CCA}, while pins B1 through B4 are referenced to V_{CCB}. Both the A port and B port can accept I/O voltages ranging from 1.65 V to 5.5 V. The high on DIR allows data transmission from Port A to Port B, and a low on DIR allows data transmission from Port B to Port A. For more information, see *AVC Logic Family Technology and Applications*.

8.2 Functional Block Diagram

To Seven Other Channels
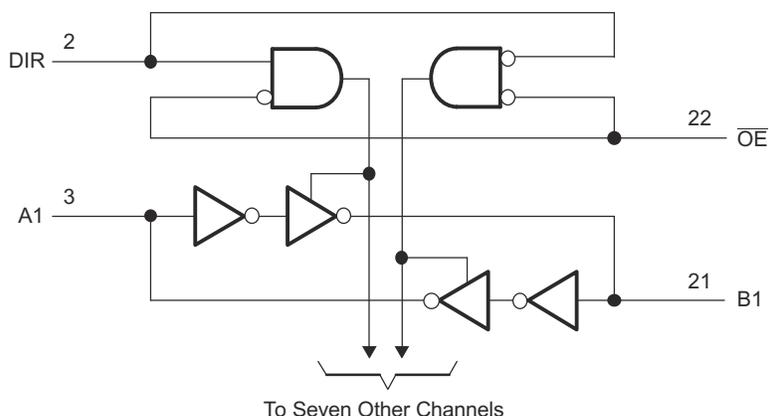
8.3 Feature Description

8.3.1 Fully Configurable Dual-Rail Design

Both V_{CCA} and V_{CCB} can be supplied at any voltage from 1.65 V to 5.5 V, making the device suitable for translating between any of the voltage nodes: 1.8 V, 2.5 V, 3.3 V, and 5 V.

8.3.2 Partial-Power-Down Mode Operation

I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. This can occur in applications where subsections of a system are powered down (partial power down) to reduce power consumption. The maximum leakage into or out of any input or output pin on the device is specified by I_{off} in the *Electrical Characteristics*.

8.3.3 Active Bus Hold Circuitry

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state, which helps with board space savings and reduced component costs. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended as this eliminates the bus-hold feature.

8.3.4 Balanced High-Drive CMOS Push-Pull Outputs

A balanced output allows the device to sink and source similar currents. The high drive capability of this device creates fast edges into light loads so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. Two outputs can be connected together for 2X stronger output drive strength. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

8.3.5 V_{CC} Isolation

The V_{CC} isolation feature ensures that if either V_{CCA} or V_{CCB} are at GND (or < 0.4 V), both ports will be in a high-impedance state (I_{OZ} shown in *Electrical Characteristics*). This prevents false logic levels from being presented to either bus.

8.4 Device Functional Modes

表 8-1 lists the functional modes of the SN74LVCH8T245.

表 8-1. Function Table (Each 8-Bit Section)

CONTROL INPUTS[1]		OUTPUT CIRCUITS		OPERATION
$\overline{OE}$	DIR	A PORT	B PORT	
L	L	Enabled	Hi-Z	B data to A bus
L	H	Hi-Z	Enabled	A data to B bus
H	X	Hi-Z	Hi-Z	Isolation

(1)   Input circuits of the data I/Os are always active.

Product Folder Links: *SN74LVCH8T245*

9 Application and Implementation

9.1 Application Information

The SN74LVCH8T245 device can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The maximum output current can be up to 32 mA when device is powered by 5 V.

9.2 Typical Application
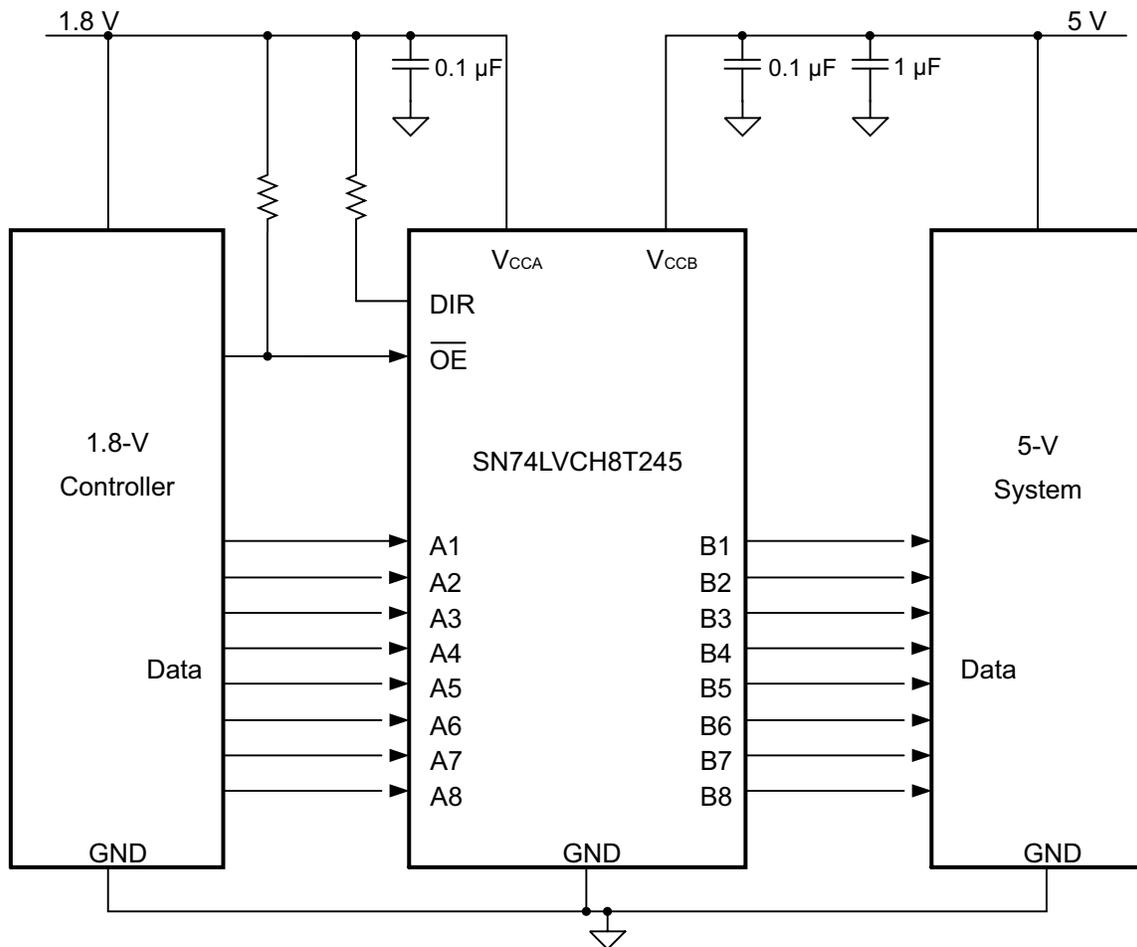
图 **9-1. Typical Application Circuit**

9.2.1 Design Requirements

For this design example, use the parameters listed in 表 9-1.

表 9-1. Design Parameters

PARAMETERS	VALUES
Input voltage	1.65 V to 5.5 V
Output voltage	1.65 V to 5.5 V

9.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
  - Use the supply voltage of the device that is driving the SN74LVCH8T245 to determine the input voltage range. For a valid logic high, the value must exceed the V_{IH} of the input port. For a valid logic low, the value must be less than the V_{IL} of the input port.
- Output voltage range
  - Use the supply voltage of the device that the SN74LVCH8T245 is driving to determine the output voltage range.

9.2.2.1 Enable Times

Calculate the enable times for the SN74LVCH8T245 using 方程式 1, 方程式 2, 方程式 3, and 方程式 4:

$$t_{PZH} \text{ (DIR to A)} = t_{PLZ} \text{ (DIR to B)} + t_{PLH} \text{ (B to A)} \tag{1}$$

$$t_{PZL} \text{ (DIR to A)} = t_{PHZ} \text{ (DIR to B)} + t_{PHL} \text{ (B to A)} \tag{2}$$

$$t_{PZH} \text{ (DIR to B)} = t_{PLZ} \text{ (DIR to A)} + t_{PLH} \text{ (A to B)} \tag{3}$$

$$t_{PZL} \text{ (DIR to B)} = t_{PHZ} \text{ (DIR to A)} + t_{PHL} \text{ (A to B)} \tag{4}$$

In a bidirectional application, these enable times provide the maximum delay from the time the DIR bit is switched until an output is expected. For example, if the device initially is transmitting from A to B, then the DIR bit is switched; the B port of the device must be disabled before presenting it with an input. After the B port has been disabled, an input signal applied to it appears on the corresponding A port after the specified propagation delay.

9.2.3 Application Curve
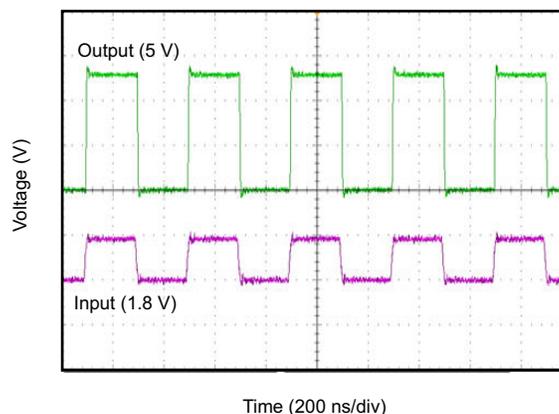
图 9-2. Translation Up (1.8 V to 5 V) at 2.5 MHz

10 Power Supply Recommendations

The output-enable ($\overline{OE}$) input circuit is designed so that it is supplied by V_{CCA} and when the $\overline{OE}$ input is high, all outputs are placed in the high-impedance state. To ensure the high-impedance state of the outputs during power up or power down, the $\overline{OE}$ input pin must be tied to V_{CCA} through a pullup resistor and must not be enabled until V_{CCA} and V_{CCB} are fully ramped and stable. The minimum value of the pullup resistor to V_{CCA} is determined by the current-sinking capability of the driver.

V_{CCA} or V_{CCB} can be powered up first. If the SN74LVCH8T245 is powered up in a permanently enabled state (for example $\overline{OE}$ is always kept low), pullup resistors are recommended at the input. This ensures proper, glitch-free, power-up. For more information, see *Designing with SN4LVCXT245 and SN74LVCHXT245 Family of Direction Controlled Voltage Translators/Level-Shifters*. In addition, the $\overline{OE}$ pin may be shorted to GND if the application does not require use of the high-impedance state at any time.

11 Layout

11.1 Layout Guidelines

To ensure reliability of the device, TI recommends the following common printed-circuit board layout guidelines.

- Bypass capacitors should be used on power supplies.
- Short trace lengths should be used to avoid excessive loading.
- Placing pads on the signal paths for loading capacitors or pullup resistors helps adjust rise and fall times of signals depending on the system requirements.

11.2 Layout Example

图 **11-1. SN74LVCH8T245 Layout**

Product Folder Links: *SN74LVCH8T245*
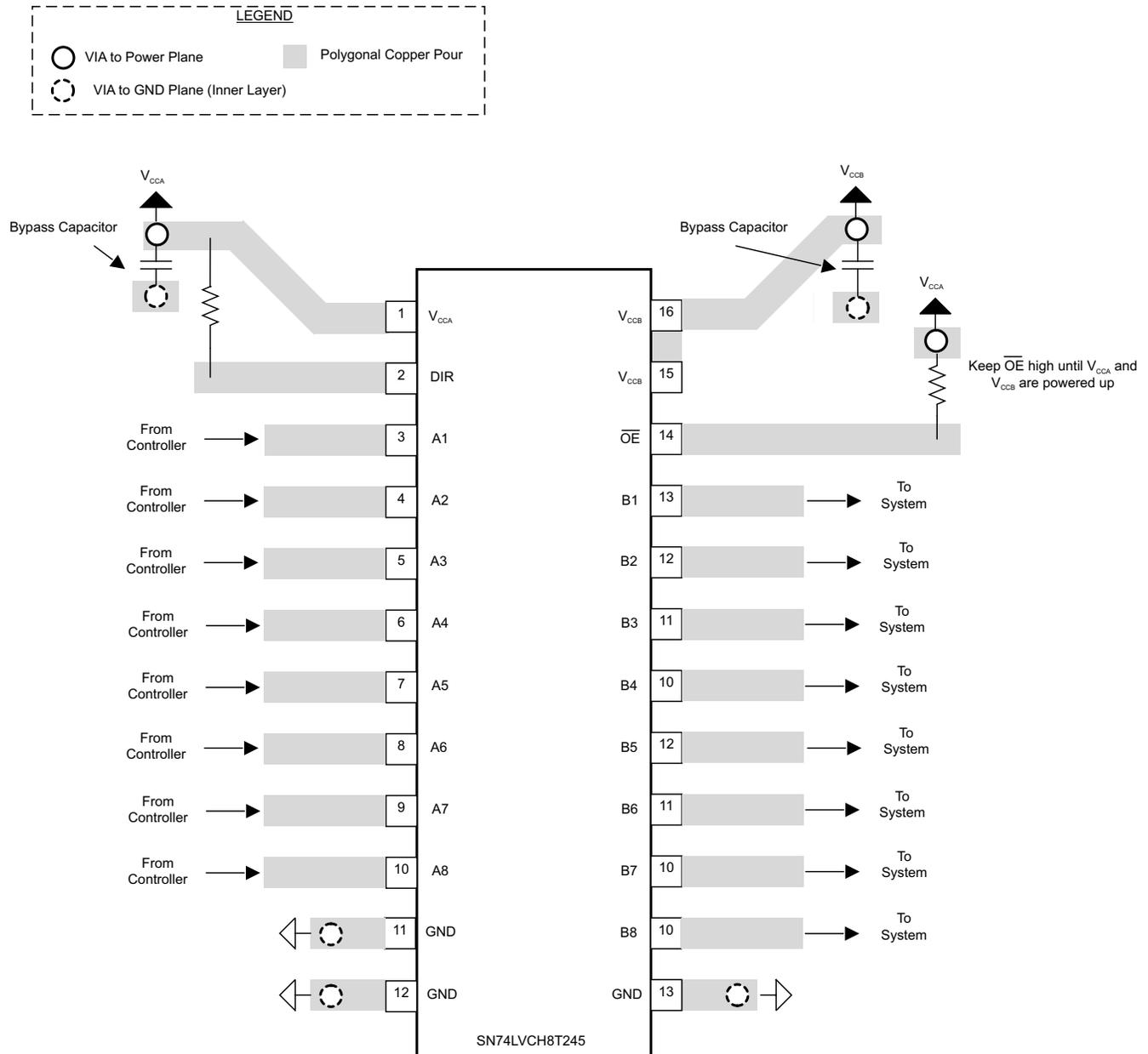
12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, *Designing with SN74LVCXT245 and SN74LVCHXT245 Family of Direction Controlled Voltage Translators/Level-Shifters*
- Texas Instruments, *Bus-Hold Circuit*
- Texas Instruments, *AVC Logic Family Technology and Applications*
- Texas Instruments, *CMOS Power Consumption and Cpd Calculation*

12.2 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击*订阅更新* 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

12.3 支持资源

TI E2E™ 支持论坛是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者"按原样"提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《使用条款》。

12.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

所有商标均为其各自所有者的财产。

12.5 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 术语表

TI 术语表   本术语表列出并解释了术语、首字母缩略词和定义。

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVCH8T245DBR	ACTIVE	SSOP	DB	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	NJ245	Samples
SN74LVCH8T245DGVR	ACTIVE	TVSOP	DGV	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	NJ245	Samples
SN74LVCH8T245PW	ACTIVE	TSSOP	PW	24	60	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	NJ245	Samples
SN74LVCH8T245PWE4	ACTIVE	TSSOP	PW	24	60	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	NJ245	Samples
SN74LVCH8T245PWR	ACTIVE	TSSOP	PW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	NJ245	Samples
SN74LVCH8T245RHLR	ACTIVE	VQFN	RHL	24	1000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NJ245	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers
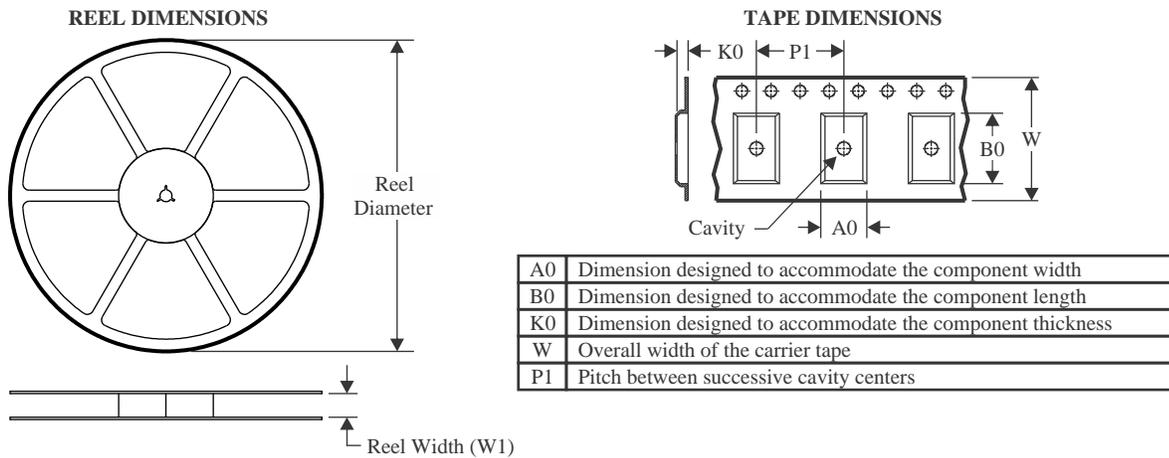
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE
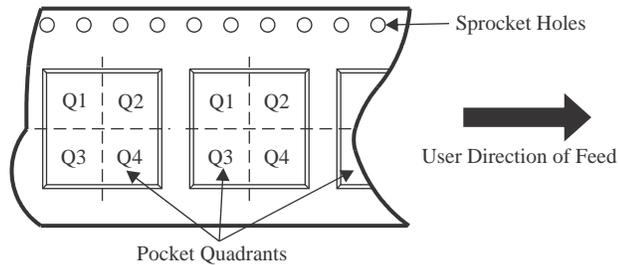
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVCH8T245DBR	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1
SN74LVCH8T245DGVR	TVSOP	DGV	24	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVCH8T245PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
SN74LVCH8T245RHLR	VQFN	RHL	24	1000	180.0	12.4	3.8	5.8	1.2	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS
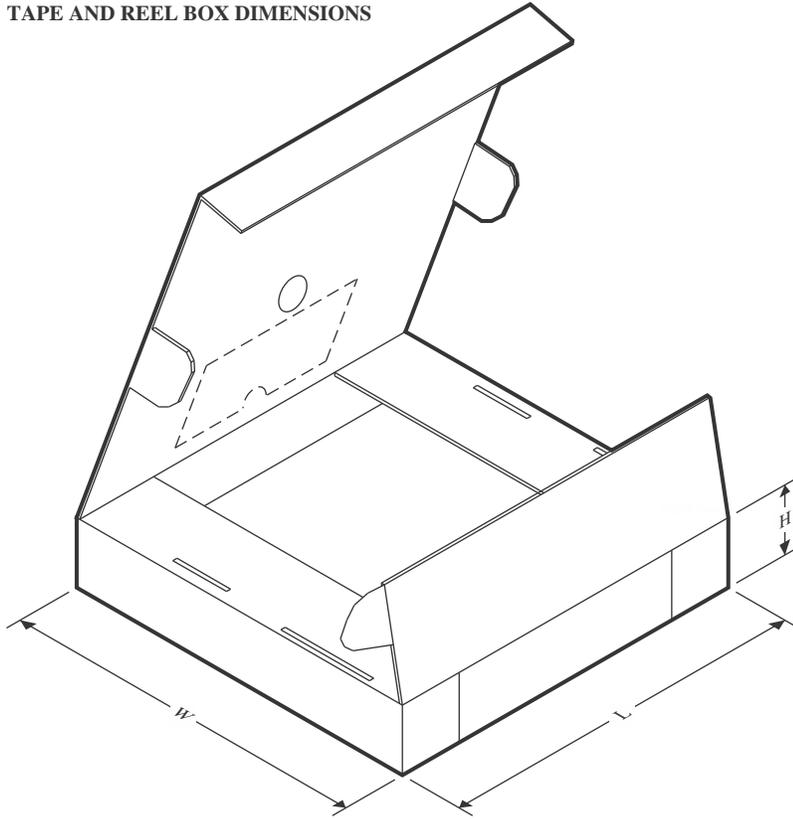
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVCH8T245DBR	SSOP	DB	24	2000	356.0	356.0	35.0
SN74LVCH8T245DGVR	TVSOP	DGV	24	2000	356.0	356.0	35.0
SN74LVCH8T245PWR	TSSOP	PW	24	2000	356.0	356.0	35.0
SN74LVCH8T245RHLR	VQFN	RHL	24	1000	210.0	185.0	35.0

TUBE

T - Tube height

L - Tube length

W - Tube width

B - Alignment groove width
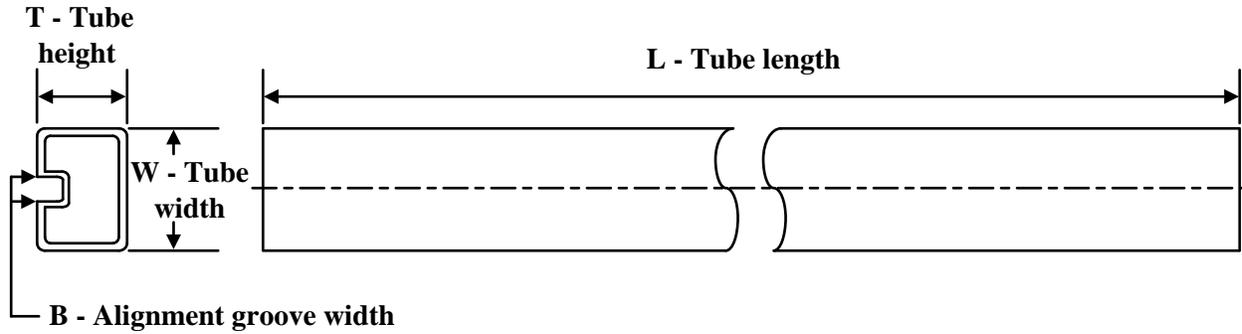
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN74LVCH8T245PW	PW	TSSOP	24	60	530	10.2	3600	3.5
SN74LVCH8T245PWE4	PW	TSSOP	24	60	530	10.2	3600	3.5

DB (R-PDSO-G**)   **PLASTIC SMALL-OUTLINE**

28 PINS SHOWN

PINS ** DIM	14	16	20	24	28	30	38
A MAX	6,50	6,50	7,50	8,50	10,50	10,50	12,90
A MIN	5,90	5,90	6,90	7,90	9,90	9,90	12,30

4040065 /E 12/01
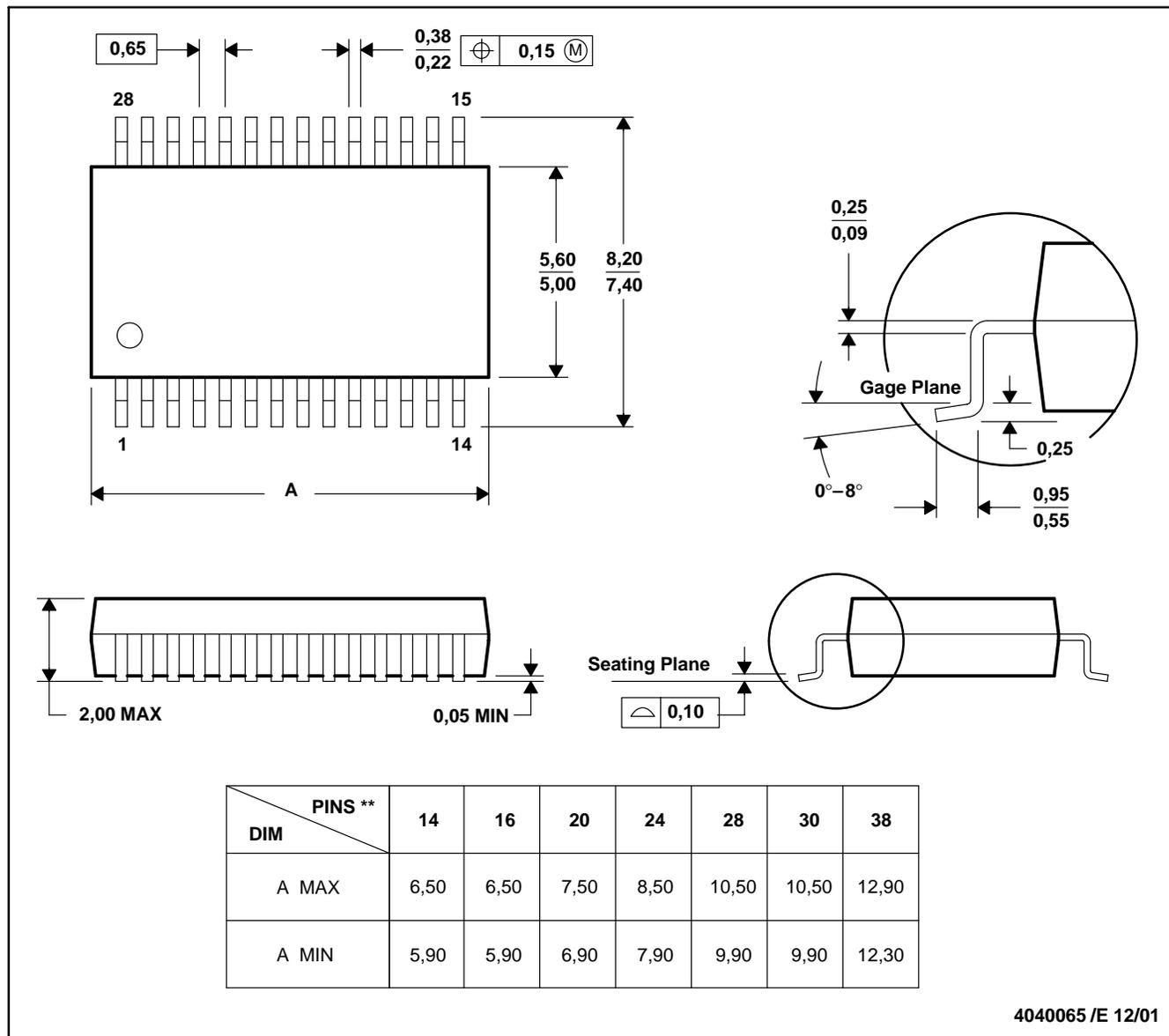
NOTES: A.   All linear dimensions are in millimeters.
B.   This drawing is subject to change without notice.
C.   Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D.   Falls within JEDEC MO-150
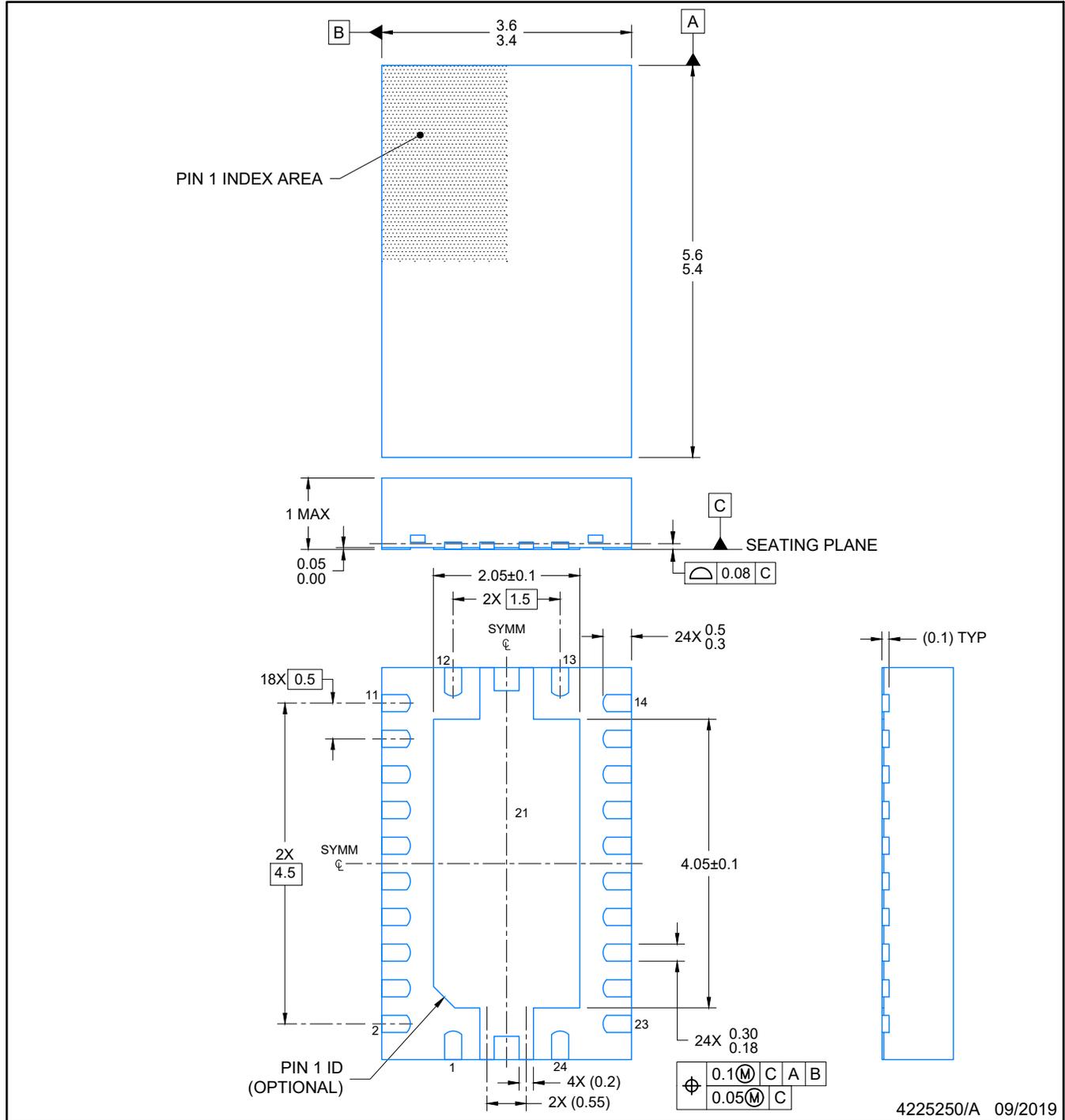
TEXAS INSTRUMENTS

POST OFFICE BOX 655303 ● DALLAS, TEXAS 75265

PLASTIC QUAD FLATPACK- NO LEAD

B | 3.6 / 3.4 | A

PIN 1 INDEX AREA

5.6 / 5.4

1 MAX

0.05 / 0.00

C

SEATING PLANE

0.08 | C

2.05±0.1

2X 1.5

SYMM

24X 0.5 / 0.3

18X 0.5

12   13

11   14

(0.1) TYP

21

2X 4.5

SYMM

4.05±0.1

2

PIN 1 ID
(OPTIONAL)

1   24   23

24X 0.30 / 0.18

4X (0.2)

2X (0.55)

0.1 Ⓜ | C | A | B
0.05 Ⓜ | C

4225250/A   09/2019

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 18X

NON SOLDER MASK
DEFINED
(PREFERRED)

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4225250/A   09/2019
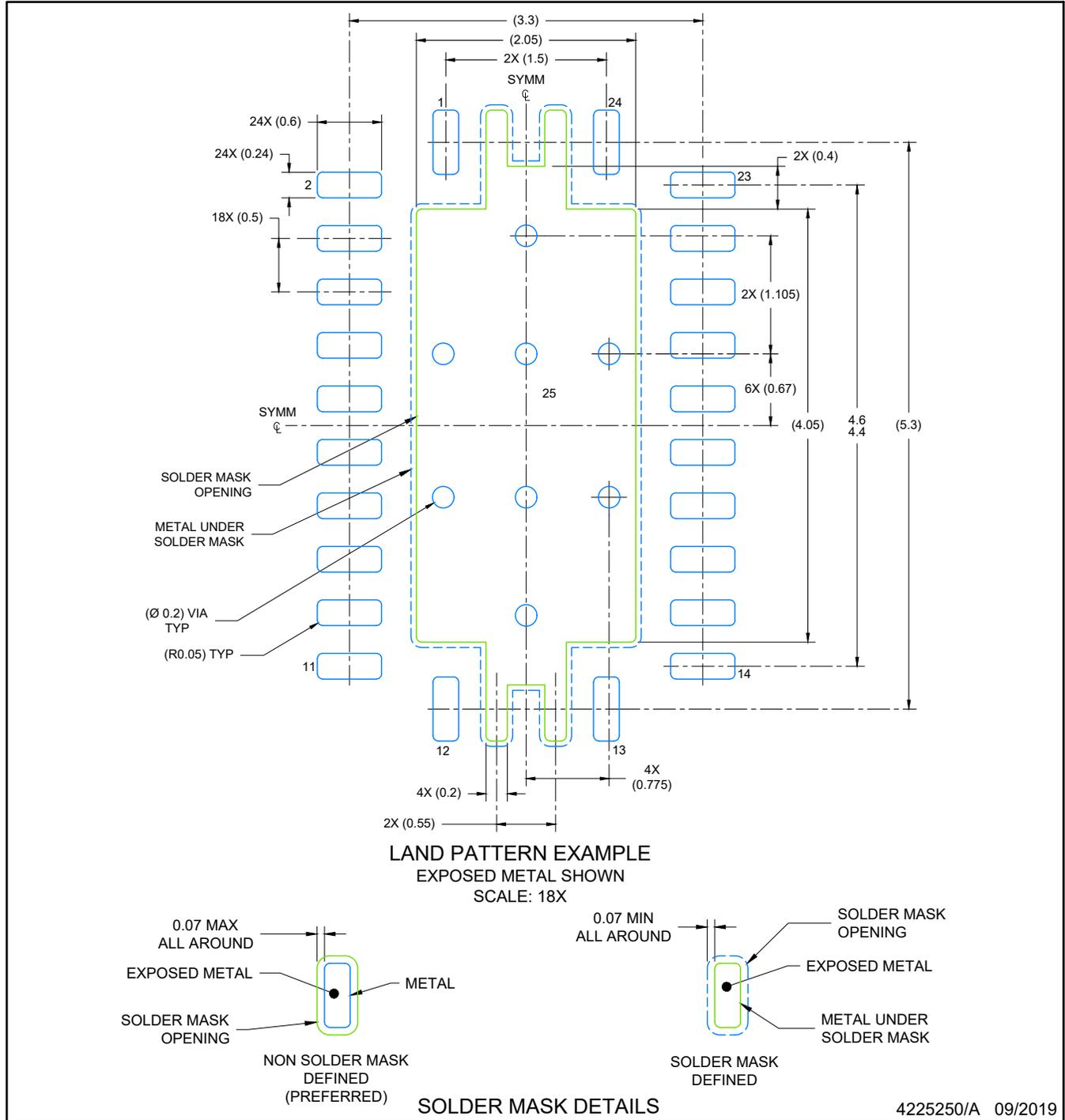
NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

PLASTIC QUAD FLATPACK- NO LEAD

(3.3)

(2.05)

2X (1.5)

SYMM

1

24

SOLDER MASK EDGE
TYP

24X (0.6)

24X (0.24)

2

18X (0.5)

23

25

SYMM

4.6
4.4

(5.3)

4X
(1.34)

METAL TYP

(R0.05) TYP

11

14

12

13

2X (0.84)

6X (0.56)

4X (0.2)

2X (0.55)
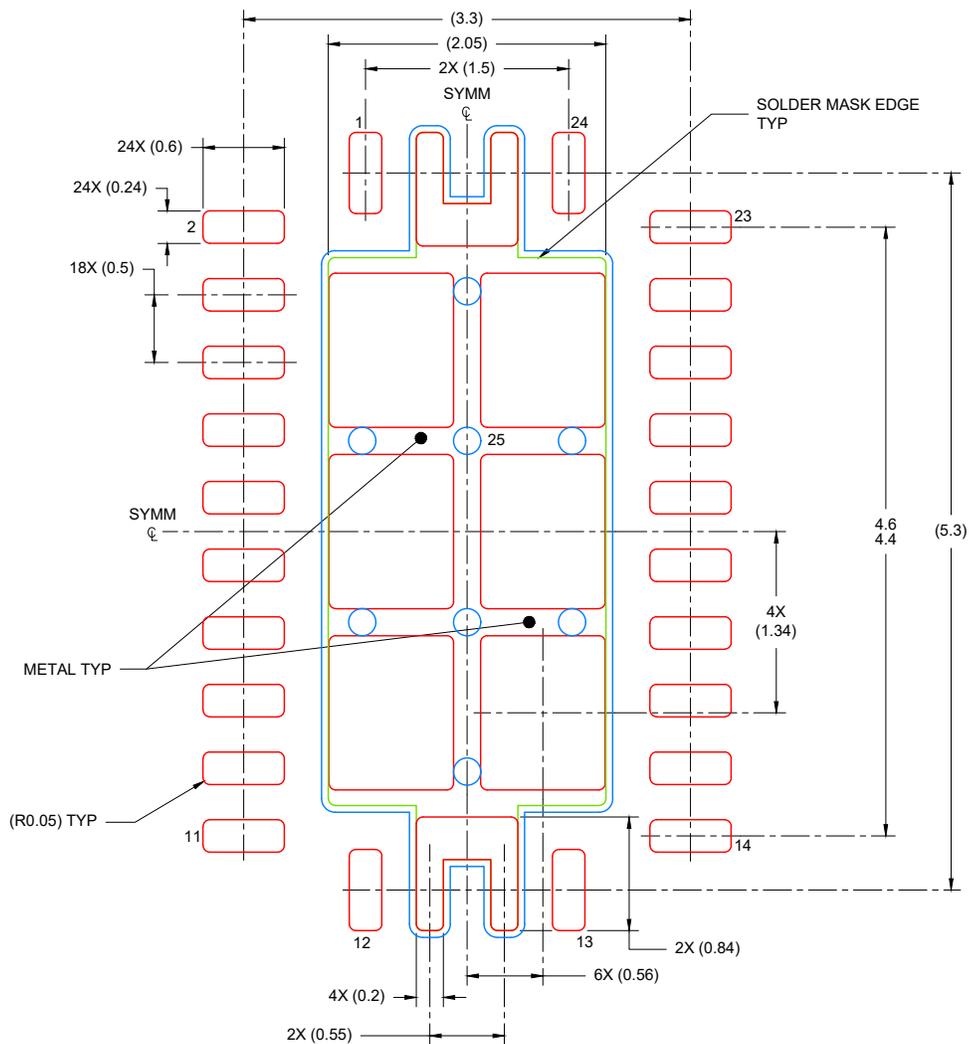
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
80% PRINTED COVERAGE BY AREA
SCALE: 18X

4225250/A   09/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
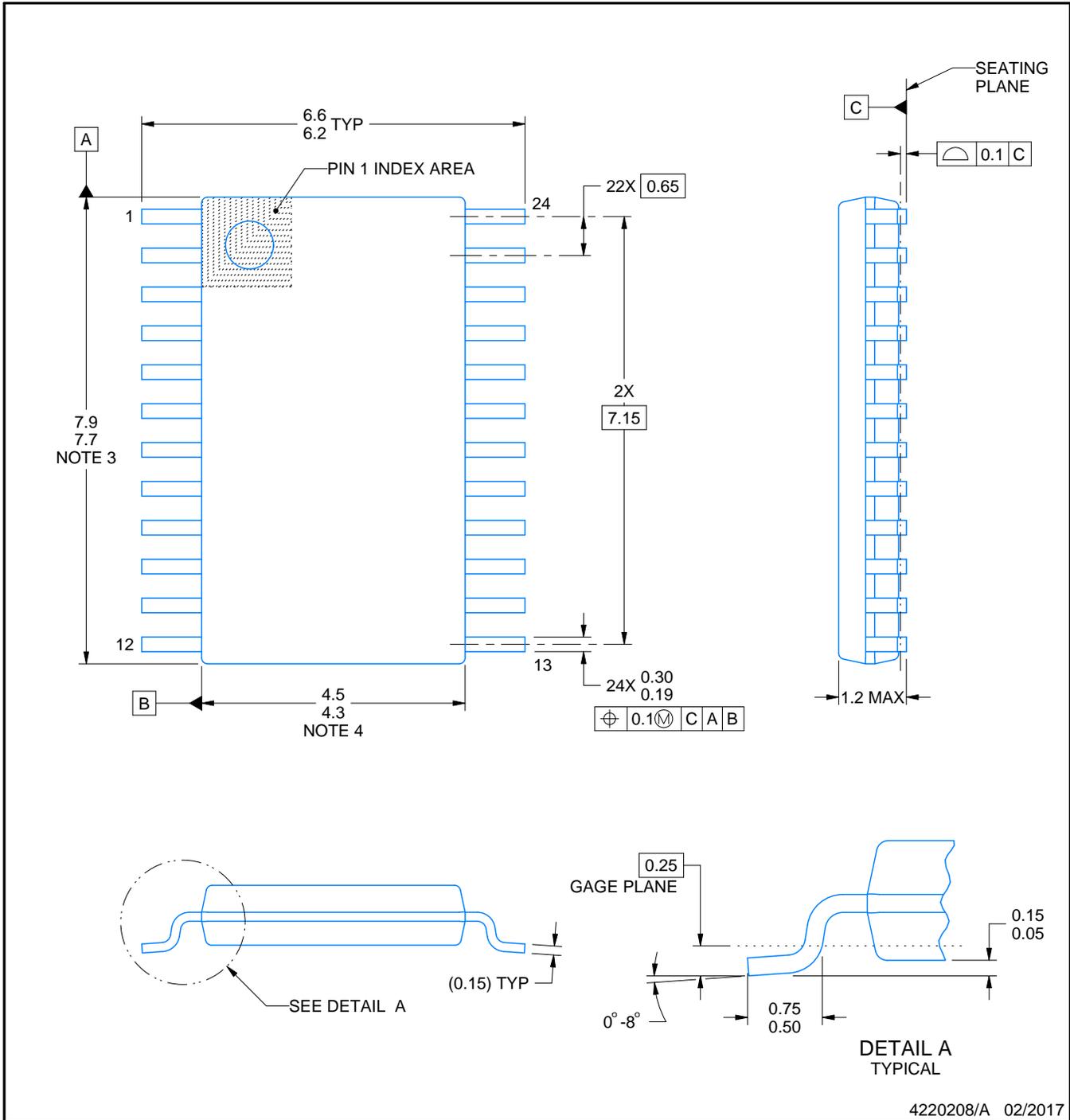
4220208/A   02/2017

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

24X (1.5)

SYMM

(R0.05) TYP

1

24X (0.45)

24

22X (0.65)

SYMM

12

13

(5.8)
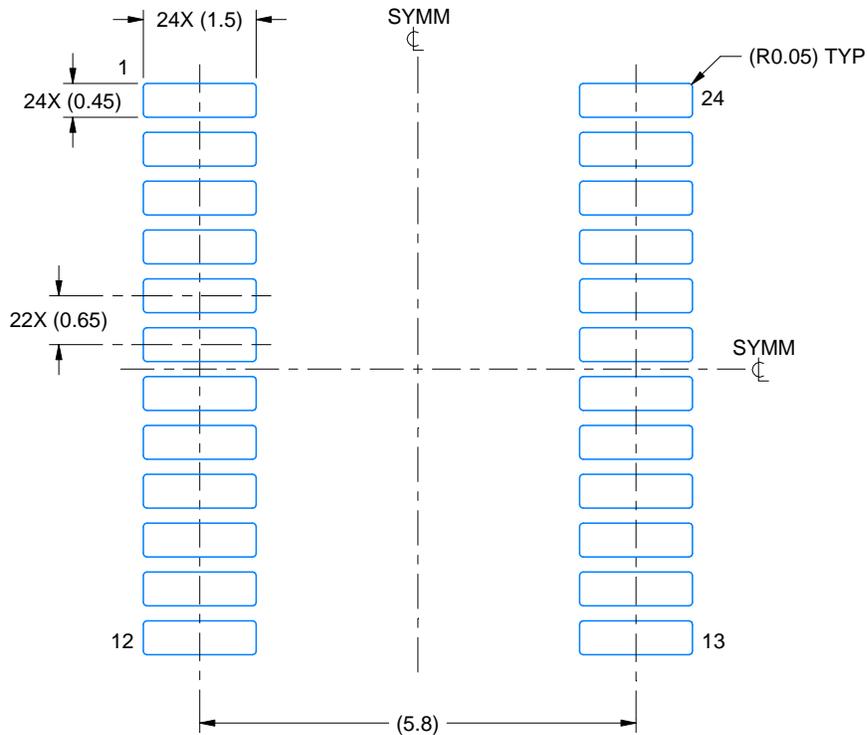
LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

SOLDER MASK
OPENING

METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

0.05 MIN
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

SOLDER MASK
DEFINED
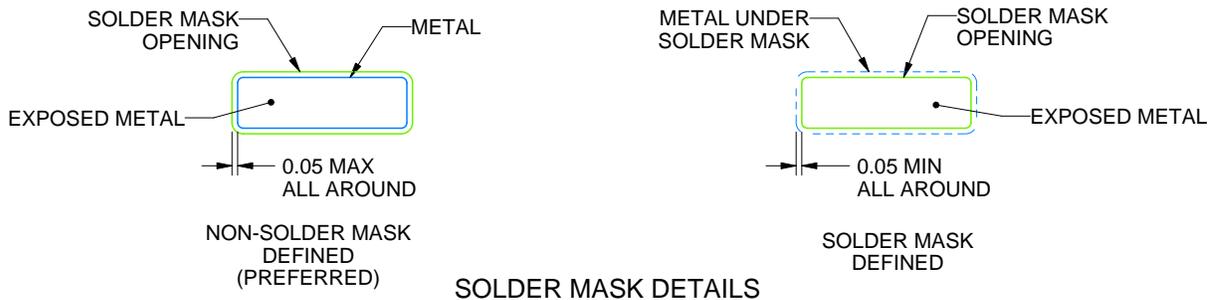
SOLDER MASK DETAILS

4220208/A   02/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

24X (1.5)

1

24X (0.45)

SYMM

(R0.05) TYP

24

22X (0.65)

SYMM

12

13

(5.8)

SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220208/A   02/2017
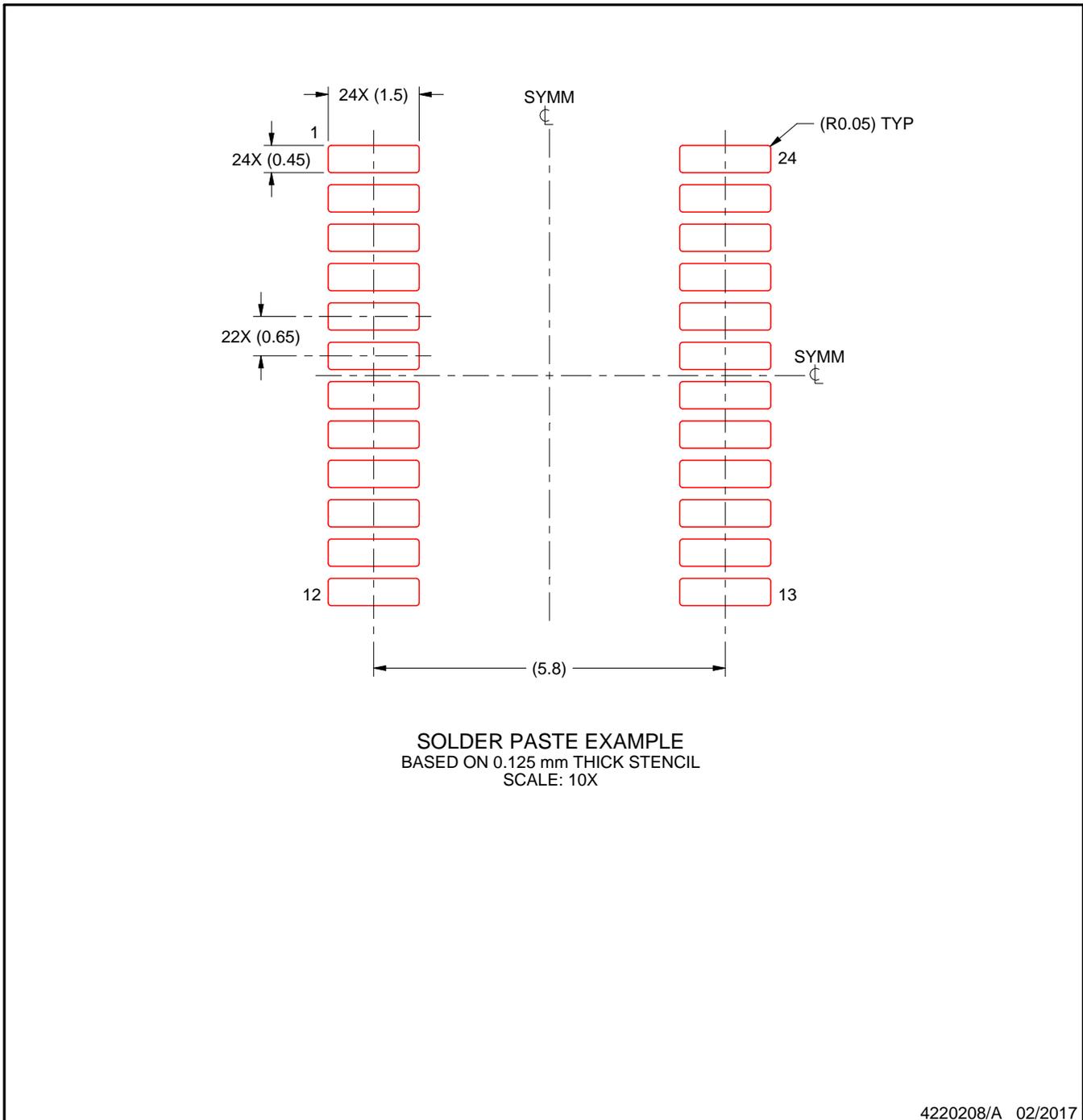
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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